

Description

The IRF630 uses advanced trench technology and design to provide excellent $R_{DS(ON)}$ with low gat e charge. It can be used in a wide variety of applications.



TO-220

General Features

 $V_{DS} = 200V, I_{D} = 9A$

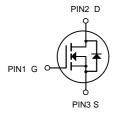
 $R_{DS(ON)} < 260 m \Omega$ @ $V_{GS}=10V$

Application

High efficiency switch mode power supplies

Power factor correction

Electronic lamp ballast



N-Channel MOSFET

Package Marking and Ordering Information

Product ID	Pack	Marking	Units Tube
IRF630	TO-220	HXY IRF630 YYYY	50

Absolute Maximum Ratings@T_j=25°C(unless otherwise specified)

Symbol	Parameter	Rating	Units
VDS	Drain-Source Voltage	200	V
VGS	Gate-Source Voltage	<u>+</u> 20	V
I _D @T _C =25°C	Drain Current	9	Α
IDM	Pulsed Drain Current ¹	36	Α
P _D @T _C =25°C	Total Power Dissipation	75	W
TSTG	Storage Temperature Range	-55 to 150	°C
TJ	Operating Junction Temperature Range	-55 to 150	°C



Electrical Characteristics (T_C=25 [°]C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage (Note 1)	BV _{DSS}	V _{GS} =0V I _D =250μA	200	-	-	V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =200V,V _{GS} =0V	-	-	1	μA
Gate-Body Leakage Current	I _{GSS}	V _{GS} =±20V,V _{DS} =0V	-	-	±100	nA
On Characteristics						
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} ,I _D =250μA	2.0	-	4.0	V
Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =10V, I _D =5A	-	220	260	mΩ
Forward Transconductance	g FS	V _{DS} =15V,I _D =4.5A	5	-	-	S
Dynamic Characteristics						
Input Capacitance	C _{lss}	\/ -25\/\/ -0\/	-	600	-	PF
Output Capacitance	Coss	V_{DS} =25V, V_{GS} =0V, F=1.0MHz	_	90	-	PF
Reverse Transfer Capacitance	C _{rss}	r-1.0ivinz	-	10	-	PF
Switching Characteristics						
Turn-on Delay Time	t _{d(on)}		-	10	-	nS
Turn-on Rise Time	t _r	V_{DD} =100 V , I_{D} =9 A	_	20	-	nS
Turn-Off Delay Time	t _{d(off)}	R_G =12 Ω , V_{GS} =10 V (Note 2)	_	25	-	nS
Turn-Off Fall Time	t _f		_	15	-	nS
Total Gate Charge	Qg	V 400V/I 0A	-	13	-	nC
Gate-Source Charge	Q _{gs}	$V_{DS}=100V,I_{D}=9A,$ $V_{GS}=10V^{(Note\ 2)}$	-	4	-	nC
Gate-Drain Charge	Q _{gd}	VGS-1UV	-	4.5	-	nC
Drain-Source Diode Characteristics			•			-
Diode Forward Voltage	V _{SD}	$V_{GS}=0V,I_{S}=9A$	-		1.5	V
Diode Forward Current (Note 2)	Is		-	-	9	Α

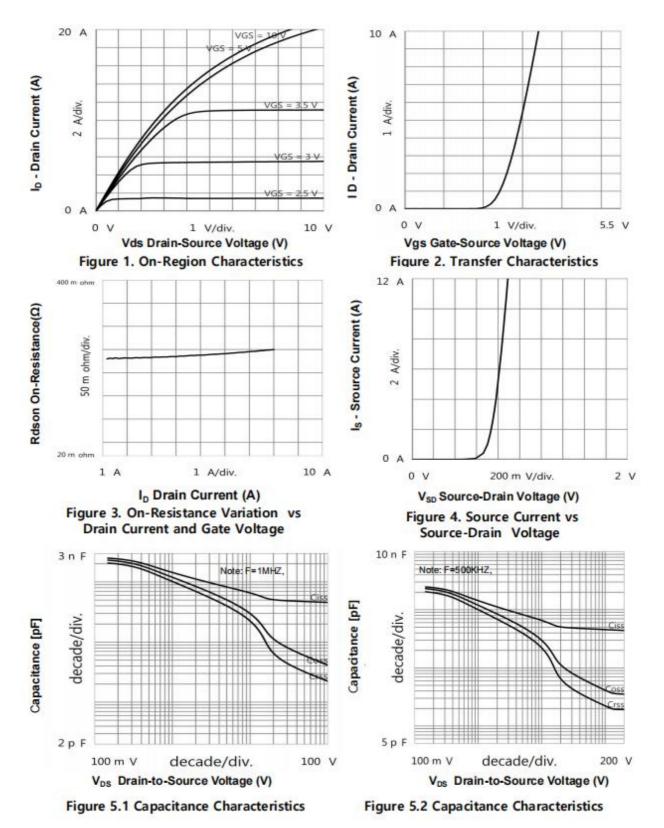
Notes:

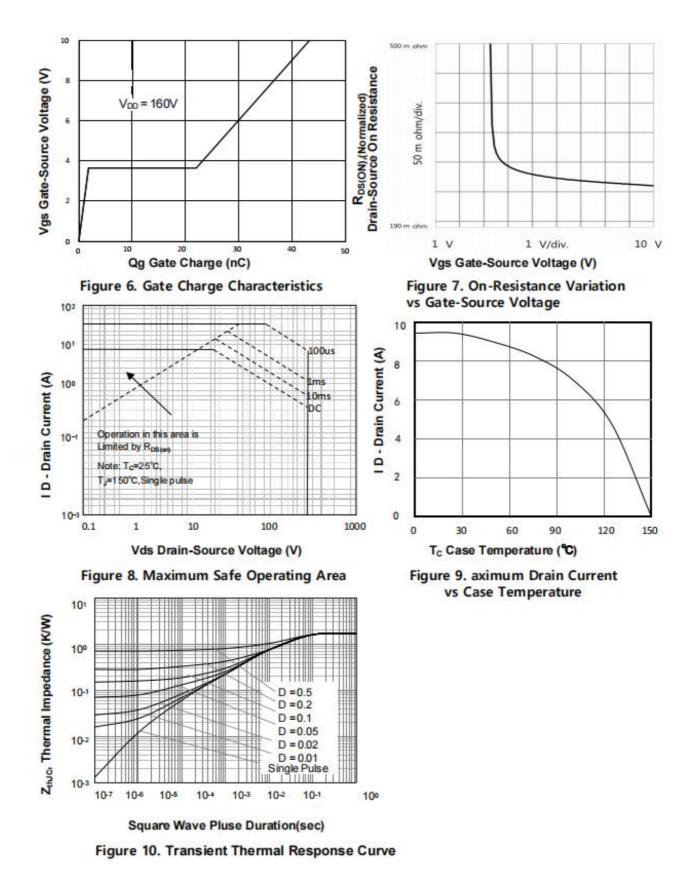
^{1.} Repetitive Rating: Pulse width limited by maximum junction temperature.

^{2.} Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 2%.



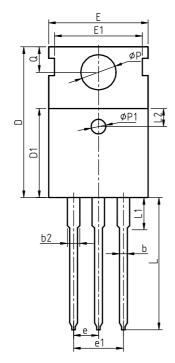
Typical Electrical

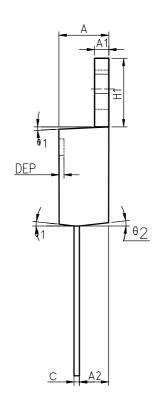




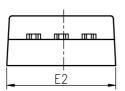


Package Information TO-220





COMMON DIMENSIONS



SYMBOL	MIN	NOM	MAX	MIN	NOM	MAX
Α	4.40	4.57	4.70	0.173	0.180	0.185
A1	1.27	1.30	1.33	0.050	0.051	0.052
A2	2.35	2.40	2.50	0.093	0.094	0.098
b	0.77	0.80	0.90	0.030	0.031	0.035
b2	1.17	1.27	1.36	0.046	0.050	0.054
С	0.48	0.50	0.56	0.019	0.020	0.022
D	15.40	15.60	15.80	0.606	0.614	0.622
D1	9.00	9.10	9.20	0.354	0.358	0.362
DEP	0.05	0.10	0.20	0.002	0.004	0.008
E	9.80	10.00	10.20	0.386	0.394	0.402
E1	-	8.70	-	-	0.343	-
E2	9.80	10.00	10.20	0.386	0.394	0.402
е		2.54	BSC		0.100	BSC
e1		5.08	BSC		0.200	BSC
H1	6.40	6.50	6.60	0.252	0.256	0.260
L	12.75	13.50	13.65	0.502	0.531	0.537
L1	ı	3.10	3.30	-	0.122	0.130
L2		2.50	REF		0.098	REF
P	3.50	3.60	3.63	0.138	0.142	0.143
P1	3.50	3.60	3.63	0.138	0.142	0.143
Q	2.73	2.80	2.87	0.107	0.110	0.113
θ 1	5°	7 °	9°	5°	7 °	9°
θ 2	1°	3°	5°	1°	3°	5°
θ 3	1°	3°	5°	1°	3°	5°

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